

Wide Band GaAs MMIC Amplifier 0.2 - 3.0 GHz

Rev. V4

Features

High Gain: 19 dB Typical Output Power: +14 dBm Typical Noise Figure: 3.7 dB Typical

RoHS* Compliant

Description

M/A-COM's MAAM02350 is a wide band, MMIC amplifier. It includes two integrated gain stages and employs resistive feedback to obtain flat gain and a 50 o h m input, and impedance match over a very wide bandwidth. The MAAM02350 operates from a single +6 V supply. It is fully monolithic.

The MAAM02350 functions well as a generic IF, driver or buffer amplifier where high gain, low noise figure, excellent linearity and low power consumption are important. Because of its wide bandwidth, the MAAM02350 can be used in numerous commercial and government system applications, such as wireless communications, EW and radar.

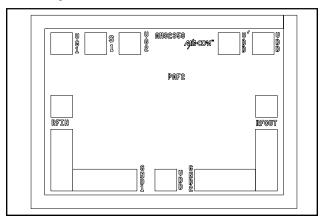
MAAM02350 is manufactured in-house using a reliable, 0.5-micron, GaAs **MESFET** process. This product is 100% RF tested to ensure compliance to performance specifications.

Absolute Maximum Ratings ^{1,2}

Parameter	Absolute Maximum		
V_{DD}	+7 V		
Input Power	+20 dBm		
Channel Temperature ³	+150°C		
Operating Temperature	-55°C to +100°C		
Storage Temperature	-65°C to +150°C		

- 1. Exceeding any one or combination of these limits may cause permanent damage to this device.
- 2. M/A-COM does not recommend sustained operation near these survivability limits.
- 3. Typical thermal resistance (θ jc) = +80°C/W.

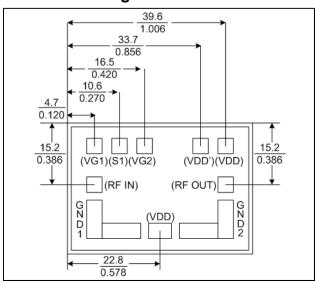
Pad Layout



Die Size—Inches (mm)

0.044 x 0.032 x 0.004 (1.140 x 0.820 x 0.102)

Outline Drawing



Ordering Information 4,5

Part Number	Package		
MAAM02350	DIE		

- 4. Reference Application Note M538 for lead-free solder reflow recommendations.
- 5. Die quantity varies.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit www.macomtech.com for additional data sheets and product information.

^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.



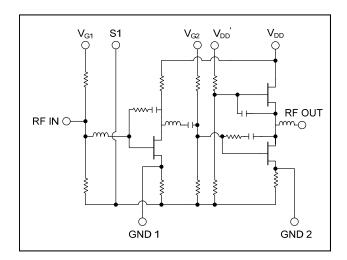
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Electrical Specifications: $T_A = 25$ °C, $V_{DD} = +6$ V, $Z_0 = 50$ Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	$0.2 - 3.0 \text{ GHz}, P_{IN} = -30 \text{ dBm}$	dB	17	19	_
Gain Flatness	0.2 - 3.0 GHz, P _{IN} = -30 dBm	dB	_	± 0.5	_
Noise Figure	0.2 - 3.0 GHz	dB		3.7	4.1
Input VSWR	$0.2 - 3.0 \text{ GHz}, P_{IN} = -30 \text{ dBm}$	Ratio		1.8:1	_
Output VSWR	$0.2 - 3.0 \text{ GHz}, P_{IN} = -30 \text{ dBm}$	Ratio		1.5:1	_
Output 1 dB Compression	0.2 - 3.0 GHz	dBm	_	+14	_
OIP3	0.2 - 3.0 GHz, P _{IN} = -30 dBm	dBm	_	24	_
Reverse Isolation	0.2 - 3.0 GHz, P _{IN} = -30 dBm	dB	_	35	_
Bias Current	_	mA	_	65	100

Schematic



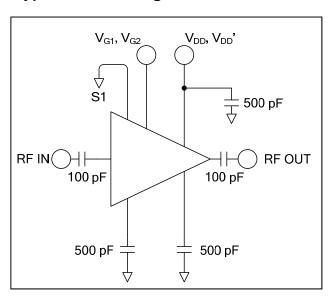
Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Typical Bias Configuration



 Self-bias operation is obtained by connecting +6 volts to both V_{DD} and V_{DD}' pads, grounding pad S1, and connecting pads GND1 and GND2 to separate bypass 500 pF MOS capacitors.

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MAAM02350

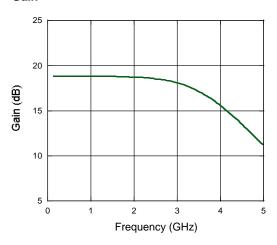


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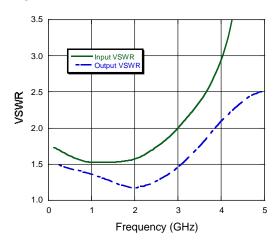
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Typical Performance @ +25°C

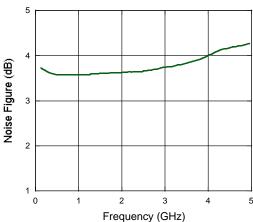
Gain



VSWR



Noise Figure



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MAAM02350



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Handling

Permanent damage to the MAAM02350 may occur if the following precautions are not adhered to:

- A. Cleanliness The MAAM02350 should be handled in a clean environment. Do not assembly attempt to clean after MAAM02350 is installed.
- B. Static Sensitivity All die handling equipment and personnel should comply with DOD-STD-1686 Class 1.
- C. Transients Avoid instrument and power supply transients while bias is connected to the MAAM02350. Use shielded signal and bias cables to minimize inductive pick-up.
- D. General Handling DO NOT touch the surface It is recommended that the of the die. MAAM02350 die be handled along the long side with a sharp pair of tweezers.

Mounting

The MAAM02350 is back-metallized with Pd/Ni/Au (100/1,000/30,000Å) metallization. It can be diemounted using Au/Sn eutectic performs or a thermally and electrically conductive epoxy. The attachment surface should be clean and flat.

Eutectic Die Attach:

- A. An 80/20 Au/Sn perform is recommended with a work surface temperature of approximately 225°C and a tool temperature of 265°C. When hot 95/5 nitrogen/hydrogen gas is applied, solder temperature should be approximately 290°C.
- B. DO NOT expose the MAAM02350 to a temperature greater than 320°C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

Epoxy Die Attach:

- A. Apply a minimum amount of epoxy and place the MAAM02350 into position. A thin epoxy fillet should be visible around the perimeter of the die.
- B. Cure epoxy per manufacturer's recommended schedule.

Bonding

- A. Ball or wedge bond with 1.0 mil diameter gold wire or 3.0 mil x 0.5 mil ribbon. Thermosonic bonding with a nominal stage temperature of 150°C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Ultrasonic energy and time should be adjusted to the minimum levels necessary to achieve reliable bonds.
- B. Bonds should be started on the die and terminated on the package. RF bonds should be as short as possible; at least three and no more than four bond wires from ground pads to package are recommended.
- C. Bonding pads are 4.0 x 4.0 mils.

Commitment to produce in volume is not guaranteed.

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ПОСТАВКА ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

многоканальный

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

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